

# Indium-doped SnO<sub>2</sub> nanoparticle–graphene nanohybrids: simple one-pot synthesis and their selective detection of NO<sub>2</sub>†

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We demonstrate novel nanohybrids of indium- and ruthenium-doped SnO<sub>2</sub> nanoparticles (NPs) on a reduced graphene oxide (RGO) surface prepared using a simple one-pot method at a relatively low temperature. The size of the doped SnO<sub>2</sub> NPs on the RGO is as small as 2–3 nm with uniform distribution. We find that the introduction of dopants facilitates the NP nucleation on graphene oxide. The gas sensing responses of the resulting nanohybrids demonstrate that the addition of indium in SnO<sub>2</sub> significantly enhances the sensitivity to NO<sub>2</sub> compared with RGO–SnO<sub>2</sub>. The sensor also shows excellent selectivity to NO<sub>2</sub> when other common gases such as NH<sub>3</sub>, H<sub>2</sub>, CO and H<sub>2</sub>S, are present. The sensing mechanism responsible for the superior sensitivity and selectivity of the nanohybrids is also discussed.

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## Introduction

Nanohybrids have been widely studied for various applications due to their enhanced mechanical, electrical, and optical properties.<sup>1–5</sup> Recently, graphene (G) and its chemically modified forms (e.g., graphene oxide) have attracted extensive attention as a nanohybrid building block because of its unique mechanical, physical, and chemical properties.<sup>6–11</sup> For example, graphene has high mechanical strength (>1060 GPa), high thermal conductivity (~3000 W m<sup>−1</sup> K<sup>−1</sup>), high electron mobility (15 000 cm<sup>2</sup> V<sup>−1</sup> s<sup>−1</sup>), and a high specific surface area (2600 m<sup>2</sup> g<sup>−1</sup>).<sup>6–9</sup> Graphene-based nanohybrids have been studied for various applications, including energy storage,<sup>12–14</sup> catalysis,<sup>15,16</sup> drug delivery,<sup>17</sup> and sensors.<sup>18,19</sup> Graphene is an especially promising gas sensing material because of its high electron mobility and high specific surface area. Various graphene–nanoparticle nanohybrids, including G–Pd, G–Pt, G–SnO<sub>2</sub>, and G–ZnO<sub>2</sub>, have been used in sensing applications.<sup>19–22</sup> These nanohybrids are usually synthesized either by *in situ* nanoparticle (NP) growth on graphene in solution or by directly mixing two previously prepared materials. However, the sensing application of graphene-based nanohybrids is still in its infancy.

Tin oxide (SnO<sub>2</sub>) is a semiconducting inorganic material with a wide band gap of 3.62 eV at 298 K, which has been widely used for sensing applications.<sup>23–25</sup> To achieve high sensitivity and selectivity, both doping and shrinking the size of the nanocrystals of SnO<sub>2</sub> have been used.<sup>26,27</sup> It is expected that doping SnO<sub>2</sub> can be an efficient way to improve sensing performance for the following reasons: (1) the charge carrier concentration of semiconducting SnO<sub>2</sub> can be dramatically increased by dopants,<sup>28,29</sup> which may facilitate the electron transfer during the interaction with gases; (2) dopants can constrain the growth of SnO<sub>2</sub> crystals, forming very fine NPs in hydrothermal methods,<sup>30</sup> which will result in a high surface-to-volume ratio of SnO<sub>2</sub> NPs that are conducive for gas sensing applications; (3) a large amount of oxygen vacancies and chemisorbed oxygen species are generated by metal dopants,<sup>31</sup> and can lead to enhanced sensing response; and (4) the sensor selectivity toward a specific gas can be greatly improved by carefully choosing the dopant. For example, the selectivity to ethanol was enhanced by doping ceria in SnO<sub>2</sub>,<sup>32</sup> and palladium-doped SnO<sub>2</sub> was designed to enhance the sensing selectivity to CH<sub>4</sub> and H<sub>2</sub>.<sup>33</sup> However, those materials work only at elevated temperatures.

Nitrogen dioxide is a toxic gas produced by combustion in power plants and automobiles that can harm human health and the environment by causing acid rain.<sup>34</sup> It has been recommended that the exposure time to 3 ppm NO<sub>2</sub> be no longer than 8 h.<sup>35</sup> However, it is still a challenge to develop efficient sensors to selectively detect low concentrations of NO<sub>2</sub> at room temperature. Indium (In) and ruthenium (Ru) are commonly used as dopants in SnO<sub>2</sub> for sensing applications. They have been demonstrated to not only improve sensing properties toward NO<sub>2</sub> but also to lower the operating temperature.<sup>36,37</sup>

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In this work, we report on a one-pot strategy to achieve facile and low-cost fabrication of a unique nanohybrid, in which In-doped SnO<sub>2</sub> (IDTO) NPs uniformly distribute on reduced graphene oxide (RGO). We investigated the crystal growth mechanism and found that dopants facilitated the nucleation of SnO<sub>2</sub> crystals on graphene oxide (GO) surface. This method also can be used to fabricate SnO<sub>2</sub> NPs doped with other elements (*e.g.*, Ru) on RGO, and potentially can be used to synthesize other doped metal oxide (*e.g.*, TiO<sub>2</sub>) or metal oxide nanocomposites on graphene. The Ru-doped SnO<sub>2</sub> NPs-RGO hybrids were also synthesized using the same method, and the control experiments further proved the role of dopants in the NP formation. The enhanced sensing performance of RGO/In-SnO<sub>2</sub> (RGO-IDTO) toward NO<sub>2</sub> was demonstrated at room temperature, reaching a detection limit as low as 0.3 ppm. Moreover, excellent selectivity was also achieved, as verified by testing several other gases with the same device. The tiny NPs offer a large number of active sites for gas adsorption, and the dopants play a critical role in enhancing sensor performance with RGO acting as a conducting channel.

## Experimental

### Synthesis

GO was prepared by oxidizing graphite powder (Bay Carbon, SP-1 graphite) under acidic conditions according to the modified Hummers method.<sup>38</sup> In a typical process to prepare RGO-IDTO, 8 mg GO was dispersed in 20 ml deionized water, and sonicated for 30 min. Then 0.5 ml InCl<sub>3</sub> (0.05 M) aqueous solution and 2.5 ml SnCl<sub>4</sub> (0.01 M) were added to the GO dispersion in sequence with magnetic stirring (400 rpm). The mixture was sonicated for 10 min to allow for uniform ion adsorption on the GO surface. After that, 15 ml NaBH<sub>4</sub> aqueous solution (30 mg per 10 ml) was added drop-wise into the above solution with stirring. Finally, the entire solution was kept at 50 °C on a hotplate for 1 h. The final product was collected by centrifuge. Ru-doped SnO<sub>2</sub> NPs decorated RGO (RGO-RDIO) were also prepared using the same method; 1 ml RuCl<sub>3</sub> (0.05 M) was used as the dopant source, and all the other chemicals and procedures were the same as those used for the RGO-IDTO synthesis.

### Characterization

The samples were characterized using a number of techniques. The crystallographic structure of as-produced nanohybrids was investigated by X-ray diffraction (XRD). Scanning electron microscopy (SEM) was carried out with a Hitachi S-4800 electron microscope at an acceleration voltage of 10 kV. The structure of as-produced nanohybrids was characterized by transmission electron microscopy (TEM) (Hitachi H-9000-NAR). High-resolution TEM (HRTEM) and selected area electron diffraction (SAED) (at an acceleration voltage of 300 kV) were used to characterize the crystal structure of the nanohybrids. Energy dispersive X-ray spectroscopy (EDS Noran Si:Li detector) was used to characterize the elemental composition. The surface chemical composition was characterized by using X-ray photoelectron spectroscopy (XPS) (HP 5950A). Raman

spectra were taken using a Raman spectrometer (Renishaw 1000B).

### Gas sensor fabrication and sensing test

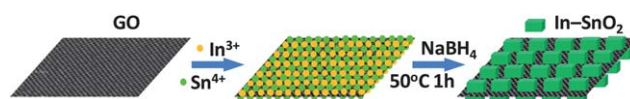
To prepare gas sensors composed of RGO-IDTO nanohybrids, gold interdigitated electrodes with finger width and inter-finger spacing of 2 μm and thickness of 50 nm were fabricated by an e-beam lithography process on a silicon wafer with a top SiO<sub>2</sub> layer of about 200 nm. The RGO-IDTO nanohybrids were dispersed in *N,N*-dimethylformamide (DMF), and then a drop (0.1 μl) of the dispersion was cast onto the gold electrode. Low concentration dispersion was used to avoid overlapping RGO sheets. To purify the sensor and improve the electrical contact between the nanohybrids and the gold electrodes, the sensor devices were annealed in a tube furnace at 200 °C for 1 h before sensing tests.

The gas sensing properties were tested in an air-tight chamber with electrical feedthroughs. A constant voltage was applied to the electrode gap bridged by the nanohybrids. Then the target gas with certified concentrations was flowed into the chamber, and the change in the current passing through the nanohybrids was monitored and recorded using a Keithley 2602 source meter (Keithley, Cleveland, OH). A typical sensing test cycle consisted of three sequential steps. First, a dry air flow was introduced into the sensing test chamber to record a baseline. Then, a target gas diluted in air was injected to register sensor signals. Finally, the sensor was recovered in a dry air flow. All the flow rates were controlled at 2 l min<sup>-1</sup>, and the target gases were diluted in dry air. The sensor sensitivity was defined as  $S = \Delta G/G_0$ , where  $\Delta G$  is the change in the sensor conductance before and after the gas exposure and  $G_0$  is the sensor conductance in dry air. The resistance of RGO-IDTO nanohybrids was ~2 kΩ (or  $G_0 = 0.0005$  S) in dry air before target gas exposure.

## Results and discussion

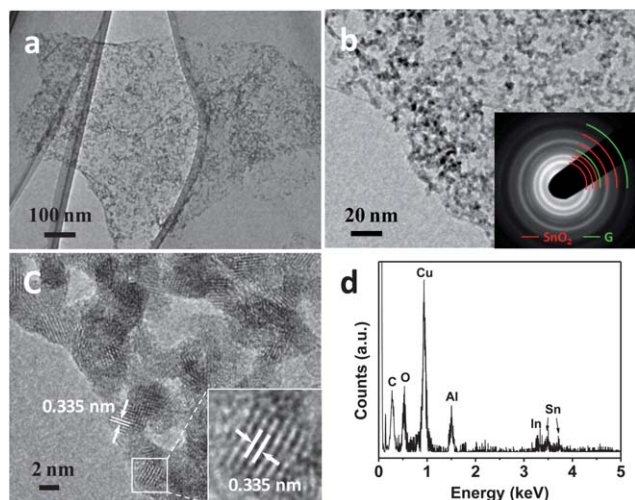
Scheme 1 illustrates the preparation procedure of RGO-IDTO nanohybrids. First, indium ions were introduced into the GO dispersion by adding an InCl<sub>3</sub> aqueous solution under magnetic stirring. Then, tin ions were slowly added into the above mixture using SnCl<sub>4</sub> aqueous solution as the source. After sonication, a NaBH<sub>4</sub> solution was slowly dropped into the solution mixture to reduce GO. The obtained solution was then continuously stirred at 50 °C for 1 h and RGO-IDTO nanohybrids were obtained after centrifuging and washing.

The morphology of as-produced RGO-IDTO nanohybrids was first examined by a field-emission SEM. An overview of the RGO-IDTO nanohybrids is shown in Fig. S1,<sup>†</sup> which clearly indicates



**Scheme 1** Schematic illustration for the preparation process of RGO-IDTO nanohybrids.

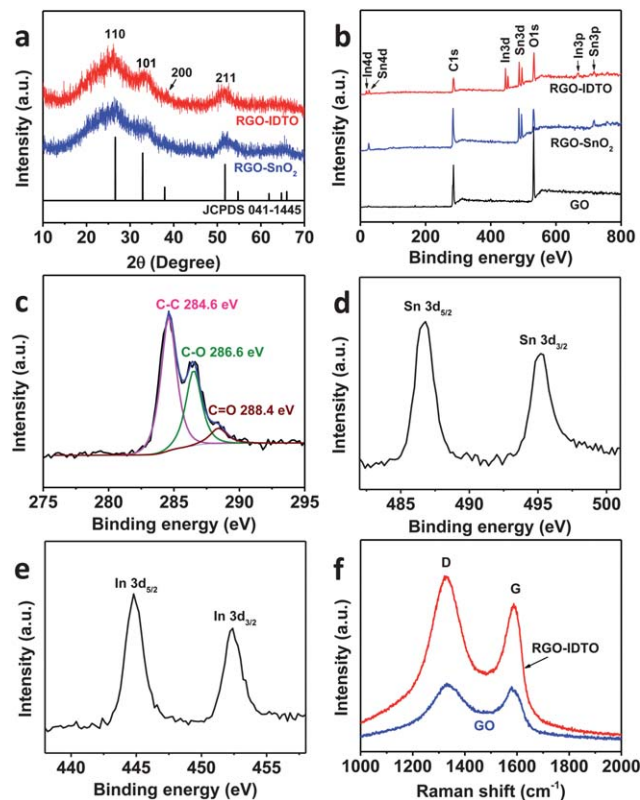




**Fig. 1** (a and b) TEM images of RGO-IDTO nanohybrids. The inset in image (b) is the SAED pattern of RGO-IDTO. The rings marked with red arcs are indexed to rutile  $\text{SnO}_2$ , and the rings marked with green arc are indexed to graphene. (c) HRTEM image of RGO-IDTO nanohybrids. (d) EDS spectra of RGO-IDTO. Cu and Al are from the sample holder.

that the nanohybrids retain the sheet structure typical for graphene. The nanostructure was further investigated using TEM (Fig. 1a), showing that the IDTO nanostructures are uniformly coated on the RGO sheet. A typical magnified TEM image is shown in Fig. 1b, demonstrating that a thin lacy network of IDTO NPs is uniformly distributed on the surface of graphene. The inset of Fig. 1b is the SAED pattern of RGO-IDTO with well-defined rings composed of two parts. The rings marked with red arcs (from the inside to outside) are indexed to rutile  $\text{SnO}_2$  (110), (101), (200), (211), and (112) planes. Meanwhile, the rings marked with green arcs (from the inside to outside) are indexed to {100}- and {110}-type reflections of graphene, consistent with graphene and with the known structure of RGO with disordered oxygen functional groups. The IDTO nanocrystals anchored on the RGO sheets were further analyzed using HRTEM. As shown in Fig. 1c, IDTO nanocrystals with clear lattice fringes are observed with sizes of about 2–3 nm. The labeled lattice spacing of 0.335 nm corresponds with the unique (110) plane of rutile  $\text{SnO}_2$ . To examine the elemental composition of NPs, EDS was performed and the result indicates that there is indium in the nanohybrid. Similar results were obtained for RGO-RDITO nanohybrids, as shown in Fig. S2.† For substitutional doping, the difference in ionic radii should be less than the Hume-Rothery limit (15%).<sup>39</sup> The ionic sizes of  $\text{Sn}^{4+}$ ,  $\text{In}^{3+}$ , and  $\text{Ru}^{4+}$  are 0.083 nm, 0.081 nm, and 0.076 nm, respectively,<sup>40,41</sup> with a maximum difference of 8.4%, which lies within the Hume-Rothery limit. Thus, when In and Ru are doped in  $\text{SnO}_2$ ,  $\text{In}^{3+}$  and  $\text{Ru}^{4+}$  can substitute for  $\text{Sn}^{4+}$ , forming a uniformly stable solid solution, consistent with previous reports.<sup>41,42</sup>

To obtain information about the average crystallographic structure, the RGO-IDTO nanohybrid was characterized using XRD (Fig. 2a). For comparison, RGO- $\text{SnO}_2$  without dopants was synthesized using a two-step method published previously.<sup>43</sup> Briefly,  $\text{Sn}^{4+}$  was introduced into the GO dispersion and adsorbed on the surface of GO bonded with oxygen functional groups (e.g., hydroxyl and carbonyl groups) by electrostatic



**Fig. 2** (a) XRD patterns of RGO- $\text{SnO}_2$  and RGO-IDTO nanohybrids. (b) XPS spectra of GO, RGO- $\text{SnO}_2$ , and RGO-IDTO nanohybrids. (c–e) High-resolution XPS spectra of C 1s (c), Sn 3d (d), and In 3d (e) of the RGO-IDTO nanohybrids. (f) Raman spectra of GO and RGO-IDTO nanohybrids.

force. Then the precipitate was collected and washed with centrifugation. The product was dried at 80 °C overnight, and RGO- $\text{SnO}_2$  was obtained after annealing treatment at 350 °C for 2 h under argon atmosphere. The XRD pattern in Fig. 2a demonstrates the presence of crystalline IDTO NPs through the diffraction peaks corresponding with the (110), (101), (200), and (211) planes of rutile  $\text{SnO}_2$  (JCPDS 041-1445). The broad peaks indicate that the nanocrystals are tiny, consistent with TEM results. There are no other peaks except for one weak peak around 25.5° corresponding to the (002) plane of few-layer RGO, suggesting that pure IDTO NPs are anchored on the surface of RGO during the synthesis. The XRD pattern of RGO-IDTO is very similar to that of RGO- $\text{SnO}_2$ , suggesting that there were no phase changes occurring and no nanoscale separation with indium doping in  $\text{SnO}_2$ , which is consistent with the previous report.<sup>29</sup> The above results suggest that the dopant ions are homogeneously distributed in the  $\text{SnO}_2$  lattice. The XRD pattern of RGO-RDITO shows similar characteristics (Fig. S3†).

The surface composition of RGO-IDTO was characterized by XPS. Fig. 2b shows the entire survey spectra of RGO-IDTO, showing the existence of C, O, In, and Sn in the nanohybrid, consistent with the EDS results. The C/O ratios were 1.8 for the initial GO and 1.6 for RGO-IDTO hybrids based on the XPS analysis. Although our electrical measurements presented later suggest that GO has been effectively reduced to RGO during the synthesis process, it is quite challenging to determine the exact





degree of reduction of GO because the oxygen signal in the XPS is from both RGO and IDTO. Fig. 2c–e show high-resolution XPS spectra of C 1s, Sn 3d, and In 3d, respectively. The complex C 1s XPS spectra can be fitted to three components with peaks centered at 284.6, 286.6, and 288.4 eV, corresponding with C–C, C–O, and C(O)O, respectively. The binding energies of C–O and C(O)O indicate the existence of oxygen groups in RGO.<sup>19</sup> Fig. 2d presents the Sn 3d level from IDTO, showing two symmetric peaks due to spin–orbit splitting with binding energies of 495.2 and 486.8 eV for the  $d_{3/2}$  and  $d_{5/2}$  lines, respectively. Similarly, the In 3d level (Fig. 2e) consists of two peaks centered at 452.4 and 444.8 eV for the  $d_{3/2}$  and  $d_{5/2}$  lines, respectively. The as-produced RGO–IDTO nanohybrid was also investigated by Raman spectroscopy (Fig. 2f). The peak at about  $1587\text{ cm}^{-1}$  (G band) corresponds to the in-plane vibration of  $sp^2$  carbon–carbon bonds while the peak at about  $1330\text{ cm}^{-1}$  (D band) is attributed to disorders and defects of the graphitic layer.<sup>44</sup> The  $D/G$  intensity ratio ( $I_D/I_G$ ) indicates the extent of  $\pi$ -conjugation and the defect density in the graphitic layer.<sup>45</sup> The increase of  $I_D/I_G$  for RGO–IDTO (1.16) compared with that of GO (1.04) suggests a decrease in the average size of  $sp^2$  domains and a high concentration of defects, possibly caused by the sonication and reduction process. This increase in  $I_D/I_G$  also agrees with other reported results.<sup>46,47</sup>

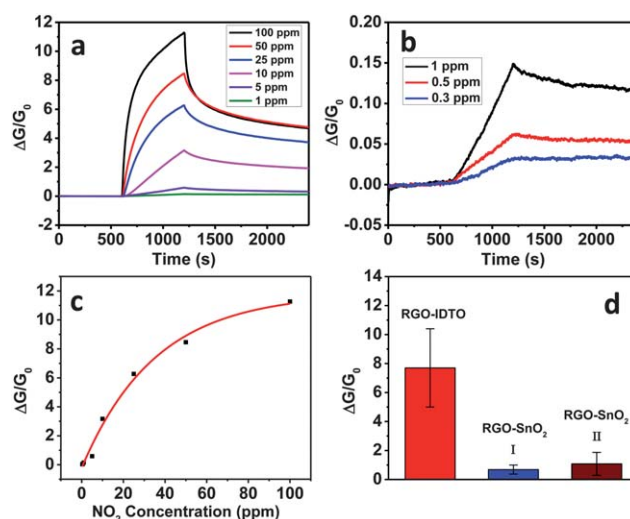
Based on our experiments, we believe that the dopant In plays a critical role in the nucleation of the doped tin oxide. For example, when only Sn and GO (no In) were used in the reaction system with the same experimental procedure, the resulting product consisted of aggregated NPs partially covering the RGO surface (Fig. S4a†). The SAED pattern in Fig. S4b† demonstrates that the NPs on RGO have poor crystalline structure, as evidenced by the broad blurry rings. When using In, the time when In is added is important, affecting the final NP dispersion and crystallization. It was found that similar well-defined RGO–IDTO nanohybrid products were obtained when mixing the two ion sources and then adding them into the GO dispersion, as well as when adding In first followed by adding Sn using the same molar ratio of  $\text{In/Sn} = 1:1$  (Fig. 1, S5a and b†). However, when adding Sn before In, the results were similar to those obtained when adding Sn only into the GO dispersion (Fig. S6†). A possible reason is that Sn adsorbs on the GO surface, occupying most of the available ion adsorption sites on the GO surface. Therefore, limited sites are left for In adsorption, resulting in the poor nanoparticle crystallization and dispersion.

Both the presence and the amount of dopant ions play a critical role in the formation of IDTO NPs on the GO surface. To investigate the effect of In on the final product, different amounts of In were used in the synthesis of IDTO NPs while keeping the same amount of Sn, *i.e.*, molar ratios of  $\text{In/Sn} = 1:1$ ,  $0.5:1$ , and  $0.3:1$ . The as-produced nanohybrids were characterized by TEM and SAED, shown in Fig. S5.† It was found that the samples with the largest amount of In ( $\text{In/Sn} = 1:1$ ) produced the best crystalline IDTO NPs on the RGO surface (Fig. S5a and b†), as evidenced by the clear nanoparticle distinction and bright sharp SAED rings. The sample synthesized with the smallest amount of In ( $\text{In/Sn} = 0.3:1$ ) produced NPs over the RGO surface with broad diffraction rings (Fig. S5e

and f†), indicating poor crystallization of IDTO nanoparticles. Therefore, it is reasonable to conclude that In can lower the nucleation energy of NPs, which means that well-defined IDTO nanocrystals would easily form on the GO surface with a higher concentration of In. We also investigated the function of Ru in the nucleation of RDTO NPs, and found that fine crystalline NPs formed on the RGO when Ru is introduced before adding Sn into the GO dispersion. With the increase of Ru in the solution, a higher density of RDTO nanoparticles formed on the RGO surface (Fig. S7†). Because the dopants encourage the final evenly distributed crystalline NPs on graphene, we propose that the IDTO/RDTO nanocrystals form at positions where dopant ions are located on the GO surface with low nucleation energy at a low temperature.

Our previous study showed that  $\text{SnO}_2$  nanocrystals enhance the sensing sensitivity of RGO to  $\text{NO}_2$ .<sup>19</sup> To prove dopants can further improve the sensing performance, we investigated the sensing properties of RGO–IDTO to  $\text{NO}_2$  at room temperature. The dynamic sensing performance of the sensor was measured under different  $\text{NO}_2$  concentrations (Fig. 3a and b). The electrical conductivity of the hybrid sensor increases upon exposure to  $\text{NO}_2$ , which is consistent with our previous results for RGO– $\text{SnO}_2$  sensors. Because  $\text{NO}_2$  is an oxidizing gas, when  $\text{NO}_2$  is adsorbed on  $\text{SnO}_2$  surface, we proposed that there is electron transfer from  $\text{SnO}_2$  to  $\text{NO}_2$ .<sup>4,19</sup> The RGO usually behaves as a p-type semiconductor in air at room temperature and was used as a conducting channel in our device.<sup>38</sup> The electron transfer effectively increases the charge carrier (*i.e.*, hole) concentration in RGO, leading to an increase in electrical conductivity. The results also demonstrate that RGO–IDTO nanohybrids show p-type semiconducting behavior, and the semiconducting type of the RGO was not changed after the IDTO NP decoration.

The sensitivity of the sensor decreases upon exposure to lower concentrations of  $\text{NO}_2$ . For the  $\text{NO}_2$  concentrations investigated (from 0.3 to 100 ppm), the sensing response can be



**Fig. 3** (a and b) Dynamic sensing response of RGO–IDTO toward different  $\text{NO}_2$  concentrations. (c) Exponential curve of sensitivity as a function of  $\text{NO}_2$  concentration. (d) Sensitivity comparison of RGO–IDTO and RGO– $\text{SnO}_2$  nanohybrids to 100 ppm  $\text{NO}_2$ .



fitted well by an exponential curve, as shown in Fig. 3c. For low concentration detection, the sensor can respond to a concentration level as low as 0.3 ppm, as shown in Fig. 3b, which is an order of magnitude lower than the EPA recommended exposure limit (3 ppm).<sup>35</sup> Our sensor thus could be used for room-temperature low concentration NO<sub>2</sub> detection. The recovery process of the sensor, however, is slow, taking overnight to completely recover to the initial state. Further sensor optimization is needed to shorten the recovery time.

To prove the sensing enhancement of dopants to NO<sub>2</sub>, the sensitivities were compared for two types of RGO-SnO<sub>2</sub> hybrids fabricated using two different methods. The first series of samples (RGO-SnO<sub>2</sub> I) were synthesized using the hydrothermal method described above.<sup>43</sup> The second series of samples (RGO-SnO<sub>2</sub> II) were synthesized by loading SnO<sub>2</sub> NPs on RGO using a mini-arc plasma source.<sup>19</sup> The sensitivity of the RGO-IDTO nanohybrids is much higher than that of RGO-SnO<sub>2</sub> (Fig. 3d), indicating that In doping in SnO<sub>2</sub> NPs can greatly enhance the sensitivity. This result can be attributed to the increase of oxygen species (*e.g.*, O<sup>δ-</sup> adsorbates) on the nanoparticle surface by introducing indium as a dopant. As investigated by density functional theory (DFT) calculations, the interaction between the SnO<sub>2</sub> surface and NO<sub>2</sub> molecules can be described as follows: NO<sub>2</sub> (gas) + O<sup>δ-</sup> = NO<sub>3</sub><sup>δ-</sup> (adsorption), where NO<sub>2</sub> is attached to O<sup>δ-</sup> on the SnO<sub>2</sub> surface, forming a NO<sub>3</sub><sup>δ-</sup> complex, with electron transfer occurring from the nanoparticle to NO<sub>2</sub>.<sup>48</sup> A higher sensitivity suggests more NO<sub>2</sub> molecular adsorption and more electron transfer from the NPs to NO<sub>2</sub>. Moreover, it has been found that dopants in SnO<sub>2</sub> increase the number of oxygen vacancies,<sup>31</sup> which in turn can easily dissociate oxygen molecules and thus form chemisorbed oxygen species.<sup>49</sup> Since our samples were exposed to air before testing, oxygen in the air might be dissociated and chemisorbed on the IDTO surface. This is also consistent with other observations that the dopant facilitates adsorption of oxygen molecules and formation of oxygen ions on the SnO<sub>2</sub> surface.<sup>50</sup> The high sensitivity might also be attributed to the tiny size of IDTO nanocrystals due to their large surface-to-volume ratio, which leads to ample adsorption sites in the sensing process and thus an enhanced sensitivity. For NO<sub>2</sub> detection, other efficient graphene-based hybrid sensors have also been reported, such as G-WO<sub>3</sub> and RGO-Cu<sub>2</sub>O sensors.<sup>51,52</sup> Our RGO-IDTO sensors reported here have a comparable lower detection limit with RGO-Cu<sub>2</sub>O sensors, which are better than G-WO<sub>3</sub> sensors. However, there was no report on the selectivity of those nanohybrids.

In order to probe the selectivity of RGO-IDTO nanohybrid sensors, the same sensor was measured against several other gases, including H<sub>2</sub>S, CO, H<sub>2</sub>, and NH<sub>3</sub>. The sensing test cycle was the same as that for measuring NO<sub>2</sub>, and the dynamic responses are shown in Fig. 4a. The sensor showed very weak response to all gases except NO<sub>2</sub>. The device conductance decreased when the sensor was exposed to NH<sub>3</sub>, indicating electron transfer from NH<sub>3</sub> to the nanohybrids. However, the exposure to other gases led to an increase of the conductance, suggesting the electron transfer is in the opposite direction, *i.e.*, from the nanohybrids to the gas molecules. The sensitivity comparison shown in Fig. 4b demonstrates that the response to other testing gases is

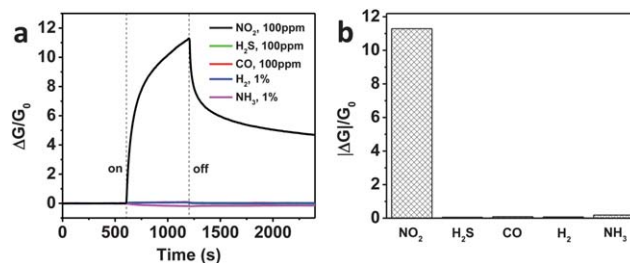


Fig. 4 Comparison of sensing responses (a) and sensitivity (b) to various gases.

negligible compared with that of NO<sub>2</sub>, indicating that our sensor has very good selectivity. Here, we suggest a “superposition effect” as one possible mechanism for the high selectivity: our previous experimental and theoretical studies showed that SnO<sub>2</sub> selectively enhanced the sensitivity of MWCNTs or RGO to NO<sub>2</sub> at room temperature.<sup>19,48</sup> It was also reported that multiple In<sub>2</sub>O<sub>3</sub> nanowire can achieve selective detection of NO<sub>2</sub> with other chemical gases such as NH<sub>3</sub>, O<sub>2</sub>, CO, and H<sub>2</sub>.<sup>53</sup> Therefore, the differential selectivity of the RGO-IDTO hybrids was maximized by doping indium in SnO<sub>2</sub> for this study due to the same gas selectivity enhancement. However, more work is needed to better understand the underlying mechanism.

## Conclusions

In summary, RGO-IDTO and RGO-RDITO nanohybrids were successfully synthesized using a simple one-pot aqueous method at low temperature. The morphology characterization results show that In- and Ru-doped SnO<sub>2</sub> NPs are evenly distributed on the RGO surface, and that the dopants are successfully incorporated into the SnO<sub>2</sub> nanocrystals. The size of the doped nanoparticles is very small, about 2–3 nm. The dopants lower the nucleation energy of the ions on GO and lead to crystalline IDTO or RDITO NPs on the RGO surface. Such nanohybrids are very promising for sensitive and selective detection of NO<sub>2</sub>. The as-prepared RGO-IDTO showed a much higher sensitivity than RGO-SnO<sub>2</sub>, indicating the sensing enhancement function of indium doping. The dopants also induced a large number of oxygen vacancies in the nanocrystals, leading to an increase in the number of surface oxygen ion species that can react with NO<sub>2</sub> gas molecules. The highly selective sensing to NO<sub>2</sub> can be understood as a “superposition effect” of selectivity in the hybrids. This preparation method opens up a simple one-pot approach to synthesize various metal-doped metal oxide nanoparticle-graphene nanohybrids for a wide range of applications such as sensors and catalysis.

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electrodes were fabricated at CNM of Argonne National Laboratory, supported by U.S. DOE (DE-AC02-06CH11357).

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